# **BLP15H9S10**; **BLP15H9S10G**

## **Power LDMOS transistor**

**AMPLEON** 

Rev. 4 — 12 January 2023

Product data sheet

### 1. Product profile

#### 1.1 General description

A 10 W LDMOS driver transistor for broadcast and industrial applications. The excellent ruggedness of this device makes it ideal for digital and analog transmitter applications in the frequency range from HF to 2 GHz.

Table 1. Typical performance

Test signal	f	V <sub>DS</sub>	$P_L$	Gp	ησ
	(MHz)	(V)	(W)	(dB)	(%)
pulsed RF	1400	50	10	21	65
	1030 to 1090	50	11	22	63
CW	360 to 450	50	10	18	60

#### 1.2 Features and benefits

- Designed for broadband operation
- High efficiency
- Integrated dual sided ESD protection
- Excellent ruggedness
- High power gain
- Excellent reliability
- Easy power control
- Excellent stability
- For RoHS compliance see the product details on the Ampleon website

#### 1.3 Applications

- Broadcast transmitter applications
- Industrial, scientific and medical applications
- Applicable at frequencies from HF to 2 GHz

### 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
BLP15H9S1	0 (TO-270-2F-1)		
1	drain	Ž	
2	gate		اً ا
3	source [1]	1	2 3 sym112
BLP15H9S1	0G (TO-270-2G-1)		*
1	drain	_ 2_	
2	gate		1
3	source [1]	1	2 - 3 3 sym112

<sup>[1]</sup> Connected to flange.

### 3. Ordering information

Table 3. Ordering information

Package name	Orderable part number	12NC	Packing description	Min. orderable quantity (pieces)
TO-270-2F-1	BLP15H9S10Z	9349 602 49515	TR13; 500-fold; 24 mm; dry pack	500
	BLP15H9S10XY	9349 602 49538	TR7; 100-fold; 24 mm; dry pack	100
TO-270-2G-1	BLP15H9S10GZ	9349 603 08515	TR13; 500-fold; 24 mm; dry pack	500
	BLP15H9S10GXY	9349 603 08538	TR7; 100-fold; 24 mm; dry pack	100

### 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	106	V
$V_{GS}$	gate-source voltage		-6	+11	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

<sup>[1]</sup> Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

### 5. Thermal characteristics

#### Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case	$T_{case} = 80 \text{ °C}; V_{DS} = 50 \text{ V}; P_{L} = 10 \text{ W}$	5.1	K/W

#### 6. Characteristics

#### Table 6. DC characteristics

 $T_i = 25$  °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.06 \text{ mA}$	106	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_D = 6.4 \text{ mA}$	1.5	2.0	2.5	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS} = 50 \text{ V}; I_D = 10 \text{ mA}$	1.5	2.0	2.5	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 50 V	-	-	1.4	μΑ
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	1.1	-	А
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 11 V; V <sub>DS</sub> = 0 V	-	-	140	nA
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 0.22 \text{ A}$	-	3.2	-	Ω

#### Table 7. RF characteristics

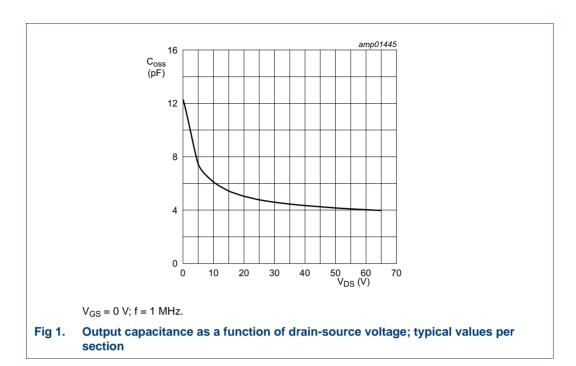
Test signal: pulsed RF;  $t_p = 100~\mu s$ ;  $\delta = 20~\%$ ; f = 1400~MHz; RF performance at  $V_{DS} = 50~V$ ;  $I_{Dq} = 10~mA$ ;  $T_{case} = 25~^{\circ}C$ ; unless otherwise specified; in a class-AB production test circuit with Johnstech socket.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P <sub>L</sub> = 10 W	19	21	-	dB
RL <sub>in</sub>	input return loss	P <sub>L</sub> = 10 W	-	-7	-3	dB
$\eta_{D}$	drain efficiency	P <sub>L</sub> = 10 W	60	65	-	%

#### Table 8. AC characteristics

 $T_i = 25$  °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C <sub>iss</sub>	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	9.8	-	pF
Coss	output capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	4.2	-	pF
C <sub>rss</sub>	reverse transfer capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	0.10	-	pF



### 7. Test information

#### 7.1 Ruggedness in class-AB operation

The BLP15H9S10 and BLP15H9S10G are capable of withstanding a load mismatch corresponding to VSWR = 30 : 1 through all phases under the following conditions:  $V_{DS} = 55 \text{ V}$ ;  $I_{Dq} = 5 \text{ mA}$ ;  $P_L = 13 \text{ W}$ ; f = 1400 MHz; pulsed CW ( $t_p = 100 \text{ } \mu \text{s}$ ;  $\delta = 20 \text{ } \%$ ).

#### 7.2 Test circuit

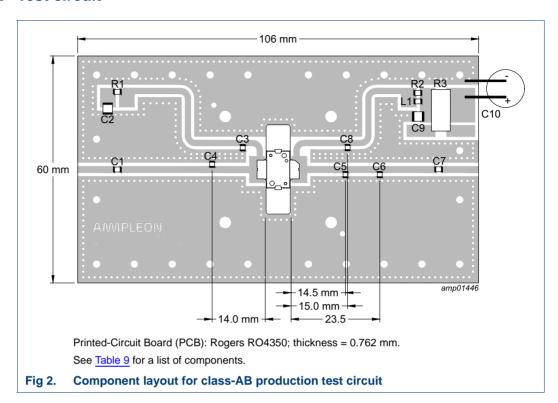


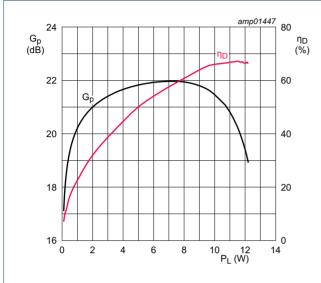
Table 9. List of components For test circuit see Figure 2.

Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	12 pF [1]	
C2, C9	multilayer ceramic chip capacitor	4.7 μF, 100 V	
C3, C7, C8	multilayer ceramic chip capacitor	30 pF [1]	
C4	multilayer ceramic chip capacitor	5.1 pF [1]	
C5	multilayer ceramic chip capacitor	7.5 pF [1]	
C6	multilayer ceramic chip capacitor	4.3 pF [1]	
C10	electrolytic capacitor	470 μF, 64 V	
R1	chip resistor	4.7 Ω	SMD 1206
R2	chip resistor	10 Ω	SMD 1206
R3	shunt resistor	0.01 Ω	
L1	inductor	9 nH	Coilcraft: 1508-9N0GLB

[1] American Technical Ceramics type 800A or capacitor of same quality.

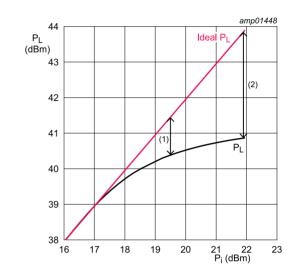
#### 7.3 Graphical data

#### 7.3.1 Pulsed CW performance measured in production RF test circuit



 $V_{DS}$  = 50 V;  $I_{Dq}$  = 5 mA; f = 1400 MHz;  $t_p$  = 100  $\mu s;$   $\delta$  = 20 %.

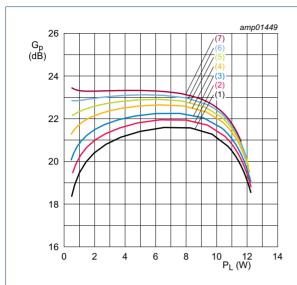
Fig 3. Power gain and drain efficiency as function of output power; typical values



 $V_{DS}$  = 50 V;  $I_{Dq}$  = 5 mA; f = 1400 MHz;  $t_p$  = 100  $\mu s;$   $\delta$  = 20 %.

- (1)  $P_{L(1dB)} = 40.4 \text{ dBm } (10.8 \text{ W})$
- (2)  $P_{L(3dB)} = 40.9 \text{ dBm } (12.2 \text{ W})$

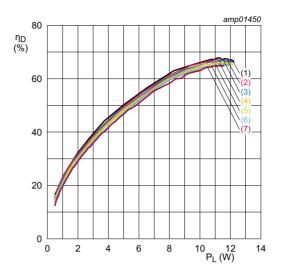
Fig 4. Output power as a function of input power; typical values



 $V_{DS} = 50 \text{ V}$ ; f = 1400 MHz;  $t_p = 100 \text{ }\mu\text{s}$ ;  $\delta = 20 \text{ }\%$ .

- (1)  $I_{Dq} = 2 \text{ mA}$
- (2)  $I_{Dq} = 5 \text{ mA}$
- (3)  $I_{Dq} = 10 \text{ mA}$
- (4)  $I_{Dq} = 20 \text{ mA}$
- (5)  $I_{Dq} = 30 \text{ mA}$
- (6)  $I_{Dq} = 40 \text{ mA}$
- (7)  $I_{Dq} = 50 \text{ mA}$

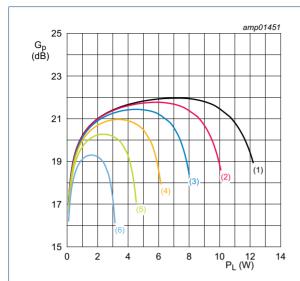
Fig 5. Power gain as a function of output power; typical values



 $V_{DS}$  = 50 V; f = 1400 MHz;  $t_p$  = 100  $\mu s;$   $\delta$  = 20 %.

- (1)  $I_{Dq} = 2 \text{ mA}$
- (2)  $I_{Dq} = 5 \text{ mA}$
- (3)  $I_{Dq} = 10 \text{ mA}$
- (4)  $I_{Dq} = 20 \text{ mA}$
- (5)  $I_{Dq} = 30 \text{ mA}$
- (6)  $I_{Dq} = 40 \text{ mA}$
- (7)  $I_{Dq} = 50 \text{ mA}$

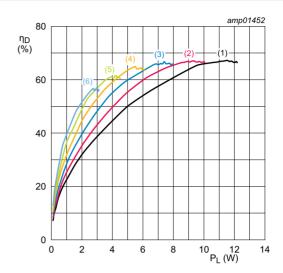
Fig 6. Drain efficiency as a function of output power; typical values



 $I_{Dq}$  = 5 mA; f = 1400 MHz;  $t_p$  = 100  $\mu s;$   $\delta$  = 20 %.

- (1)  $V_{DS} = 50 \text{ V}$
- (2)  $V_{DS} = 45 \text{ V}$
- (3)  $V_{DS} = 40 \text{ V}$
- (4)  $V_{DS} = 35 \text{ V}$
- (5)  $V_{DS} = 30 \text{ V}$
- (6)  $V_{DS} = 25 \text{ V}$

Fig 7. Power gain as a function of output power; typical values



 $I_{Dq}$  = 5 mA; f = 1400 MHz;  $t_p$  = 100  $\mu s;$   $\delta$  = 20 %.

- (1)  $V_{DS} = 50 \text{ V}$
- (2)  $V_{DS} = 45 \text{ V}$
- (3)  $V_{DS} = 40 \text{ V}$
- (4)  $V_{DS} = 35 \text{ V}$
- (5)  $V_{DS} = 30 \text{ V}$
- (6)  $V_{DS} = 25 \text{ V}$

Fig 8. Drain efficiency as a function of output power; typical values

### 8. Package outline

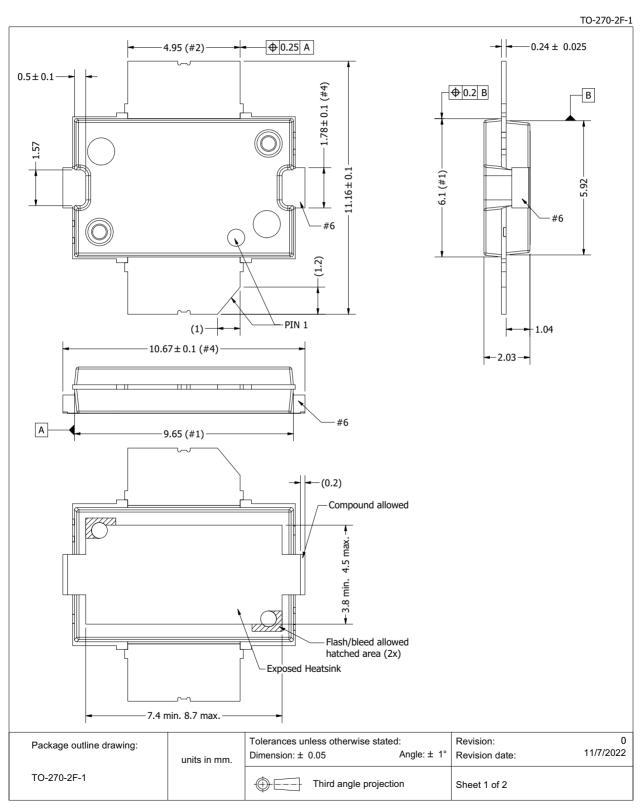
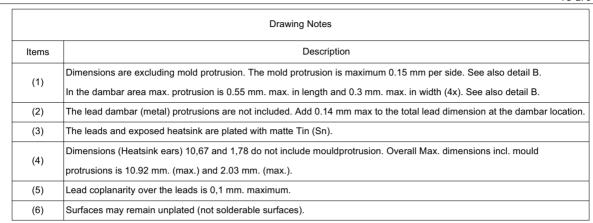


Fig 9. Package outline TO-270-2F-1 (sheet 1 of 2)

BLP15H9S10\_BLP15H9S10G

TO-270-2F-1



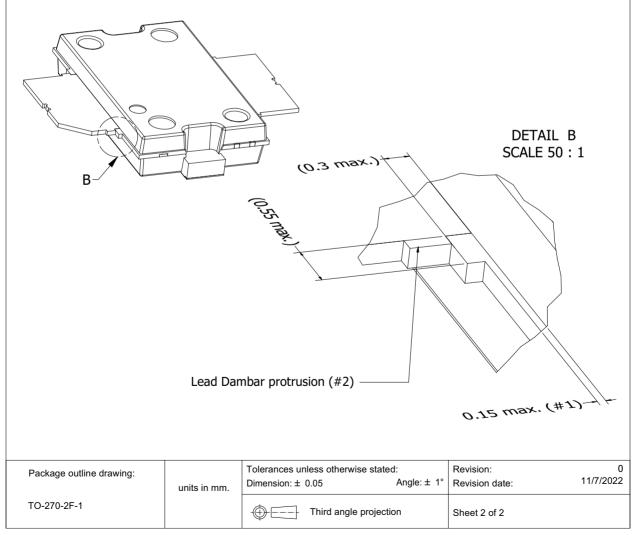


Fig 10. Package outline TO-270-2F-1 (sheet 2 of 2)

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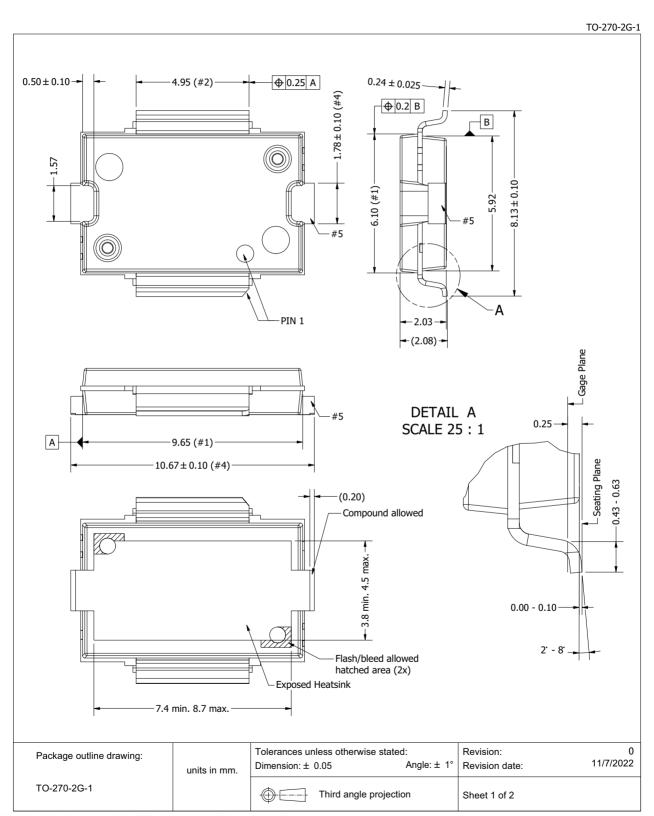
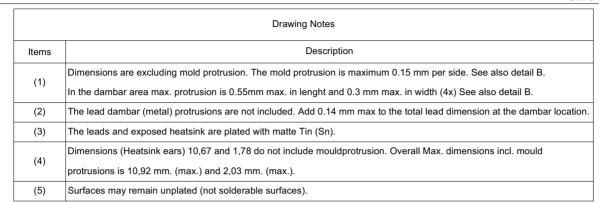


Fig 11. Package outline TO-270-2G-1 (sheet 1 of 2)

#### TO-270-2G-1



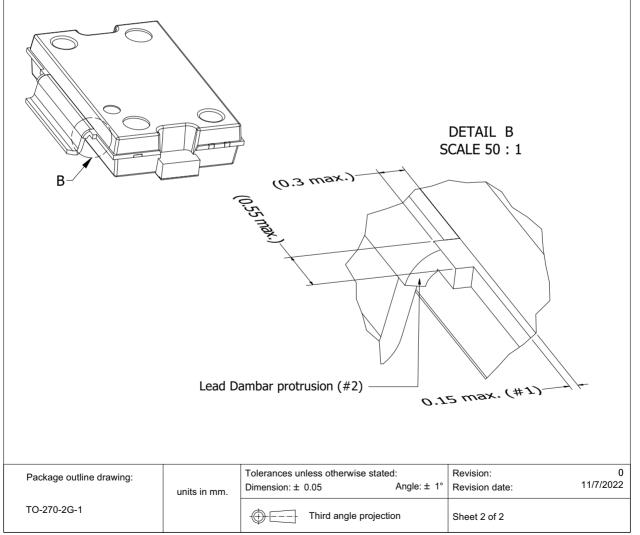


Fig 12. Package outline TO-270-2G-1 (sheet 2 of 2)

### 9. Handling information

#### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 10. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2B [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	1C [2]

- [1] CDM classification C2B is granted to any part that passes after exposure to an ESD pulse of 750 V.
- [2] HBM classification 1C is granted to any part that passes after exposure to an ESD pulse of 1000 V.

#### 10. Abbreviations

Table 11. Abbreviations

Acronym	Description
CW	Continuous Wave
ESD	ElectroStatic Discharge
HF	High Frequency
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
RoHS	Restriction of Hazardous Substances
SMD	Surface Mounted Device
VSWR	Voltage Standing Wave Ratio

## 11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLP15H9S10_BLP15H9S10G v.4	20230112	Product data sheet	-	BLP15H9S10_BLP15H9S10G v.3	
Modifications:	<ul> <li><u>Table 2 on page 2</u>: package names changed from SOT1482-1 to TO-270-2F-1 ar from SOT1483-1 to TO-270-2G-1</li> </ul>				
	<ul> <li>Table 3 on page 2: package names changed from SOT1482-1 to TO-270-2F-1 an from SOT1483-1 to TO-270-2G-1</li> </ul>				
	Table 5 on	page 3: value chang	ged from 6.0 K/W	to 5.1 K/W	
		on page 9: package of 1 and from SOT148	•	nanged from SOT1482-1 to G-1	
	Section 12	on page 14: update	d section		
BLP15H9S10_BLP15H9S10G v.3	20210708	Product data sheet	-	BLP15H9S10_BLP15H9S10G v.2	
BLP15H9S10_BLP15H9S10G v.2	20201210	Product data sheet	-	BLP15H9S10_BLP15H9S10G v.1	
BLP15H9S10_BLP15H9S10G v.1	20200929	Product data sheet	-	-	

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#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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#### **Power LDMOS transistor**

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# **BLP15H9S10**; **BLP15H9S10G**

**Power LDMOS transistor** 

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